

Vishay General Semiconductor

TRANSZORB® Transient Voltage Suppressors



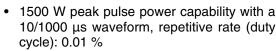
| PRIMARY CHARACTERISTICS | | | | |
|-------------------------|---------------|--|--|--|
| V _{WM} | 5.0 V to 18 V | | | |
| P _{PPM} | 1500 W | | | |
| P _D | 6.5 W | | | |
| I _{FSM} | 200 A | | | |
| T _J max. | 175 °C | | | |

DEVICES FOR BI-DIRECTION APPLICATIONS

For bi-directional types, use C suffix (e.g. ICTE-18C). Electrical characteristics apply in both directions.

FEATURES

- Glass passivated chip junction
- · Available in uni-directional and bi-directional





COMPLIANT

· Excellent clamping capability

- · Very fast response time
- · Low incremental surge resistance
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial and telecommunication.

MECHANICAL DATA

Case: Molded epoxy body over passivated junction Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, high reliability/ automotive grade (AEC Q101 qualified)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: For uni-directional types the color band denotes cathode end, no marking on bi-directional types

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|--|-----------------------------------|----------------|------|--|--|--|--|
| PARAMETER | SYMBOL | LIMIT | UNIT | | | | |
| Peak pulse power dissipation with a 10/1000 μs waveform ⁽¹⁾ (Fig. 1) | P _{PPM} | 1500 | W | | | | |
| Peak pulse current with a 10/1000 µs waveform (1) (Fig. 3) | I _{PPM} | See next table | Α | | | | |
| Power dissipation on infinite heatsink at T _L = 75 °C (Fig. 8) | P _D | 6.5 | W | | | | |
| Peak forward surge current 8.3 ms single half sine-wave uni-directional only (2) | I _{FSM} | 200 | Α | | | | |
| Maximum instantaneous forward voltage at 100 A for uni-directional only | V _F | 3.5 | V | | | | |
| Operating junction and storage temperature range | T _J , T _{STG} | - 55 to + 175 | °C | | | | |

Notes

- (1) Non-repetitive current pulse, per Fig. 3 and derated above T_A = 25 °C per Fig. 2
- (2) 8.3 ms single half sine-wave, duty cycle = 4 pulses per minute maximum

ICTE5.0 thru ICTE18C, 1N6373 thru 1N6386

Vishay General Semiconductor



| ELECTRICAL CHARACTERISTICS (JEDEC REGISTERED DATA) ($T_A = 25$ °C unless otherwise noted) | | | | | | | |
|---|---|---|--|--|--|---|------------------------------------|
| JEDEC TYPE NUMBER | GENERAL SEMICONDUCTOR PART NUMBER | STAND-OFF VOLTAGE V _{WM} (V) | MINIMUM ⁽³⁾ BREAKDOWN VOLTAGE AT 1.0 mA V _{BR} (V) | MAXIMUM REVERSE LEAKAGE AT V _{WM} I _D (µA) | MAXIMUM CLAMPING VOLTAGE AT I _{PP} = 1.0 A V _C (V) | MAXIMUM CLAMPING VOLTAGE AT IPP = 10 A V _C (V) | MAXIMUM PEAK PULSE CURRENT IPP (A) |
| UNI-DIRECT | IONAL TYPES | | | | | | |
| 1N6373 ⁽²⁾ | ICTE-5 (2) | 5.0 | 6.0 | 300 | 7.1 | 7.5 | 160 |
| 1N6374 | ICTE-8 | 8.0 | 9.4 | 25.0 | 11.3 | 11.5 | 100 |
| 1N6375 | ICTE-10 | 10.0 | 11.7 | 2.0 | 13.7 | 14.1 | 90 |
| 1N6376 | ICTE-12 | 12.0 | 14.1 | 2.0 | 16.1 | 16.5 | 70 |
| 1N6377 | ICTE-15 | 15.0 | 17.6 | 2.0 | 20.1 | 20.6 | 60 |
| 1N6378 | ICTE-18 | 18.0 | 21.2 | 2.0 | 24.2 | 25.2 | 50 |
| BI-DIRECTIO | BI-DIRECTIONAL TYPES | | | | | | |
| 1N6382 | ICTE-8C | 8.0 | 9.4 | 50.0 | 11.4 | 11.6 | 100 |
| 1N6383 | ICTE-10C | 10.0 | 11.7 | 2.0 | 14.1 | 14.5 | 90 |
| 1N6384 | ICTE-12C | 12.0 | 14.1 | 2.0 | 16.7 | 17.1 | 70 |
| 1N6385 | ICTE-15C | 15.0 | 17.6 | 2.0 | 20.8 | 21.4 | 60 |
| 1N6386 | ICTE-18C | 18.0 | 21.2 | 2.0 | 24.8 | 25.5 | 50 |

Notes:

- (1) "C" Suffix indicates bi-directional
- (2) ICTE-5 and 1N6373 are not available as bi-directional
- (3) The minimum breakdown voltage as shown takes into consideration the ± 1 V tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Please consult factory for devices that require reduced clamping voltages where tighter regulated power supply voltages are employed
- (4) Clamping factor: 1.33 at full rated power; 1.20 at 50 % rated power; Clamping factor: the ratio of the actual V_C (Clamping Voltage) to the V_{BR} (Breakdown Voltage) as measured on a specific device

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|-----------------|------------------------|---------------|----------------------------------|--|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | | |
| ICTE-5-E3/54 | 0.968 | 54 | 1400 | 13" diameter paper tape and reel | | | |
| ICTE-5HE3/54 (1) | 0.968 | 54 | 1400 | 13" diameter paper tape and reel | | | |

Note:

(1) Automotive grade AEC Q101 qualified

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

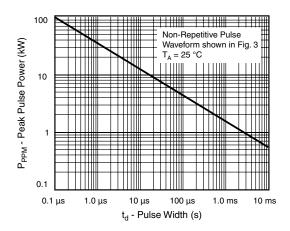


Figure 1. Peak Pulse Power Rating Curve

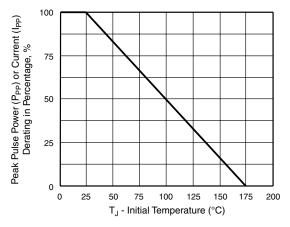


Figure 2. Pulse Power or Current vs. Initial Junction Temperature

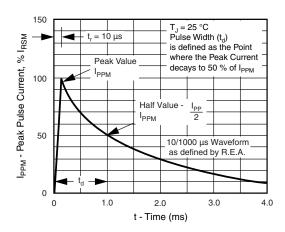


Figure 3. Pulse Waveform

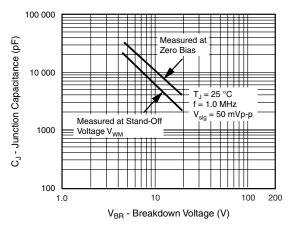


Figure 4. Typical Junction Capacitance Uni-Directional

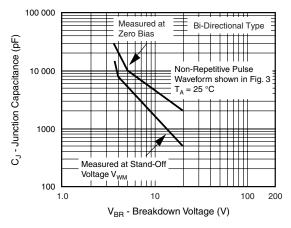


Figure 5. Typical Junction Capacitance

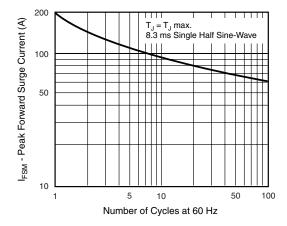


Figure 6. Maximum Non-Repetitive Forward Surge Current Uni-Directional Only

ICTE5.0 thru ICTE18C, 1N6373 thru 1N6386

Vishay General Semiconductor



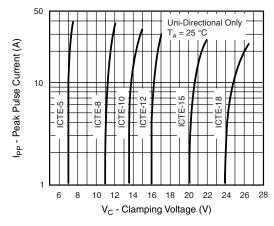


Figure 7. Typical Characteristics Clamping Voltage

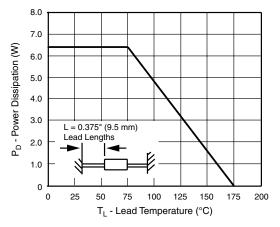
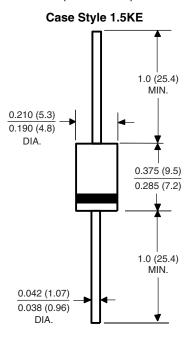


Figure 8. Power Derating Curve

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com